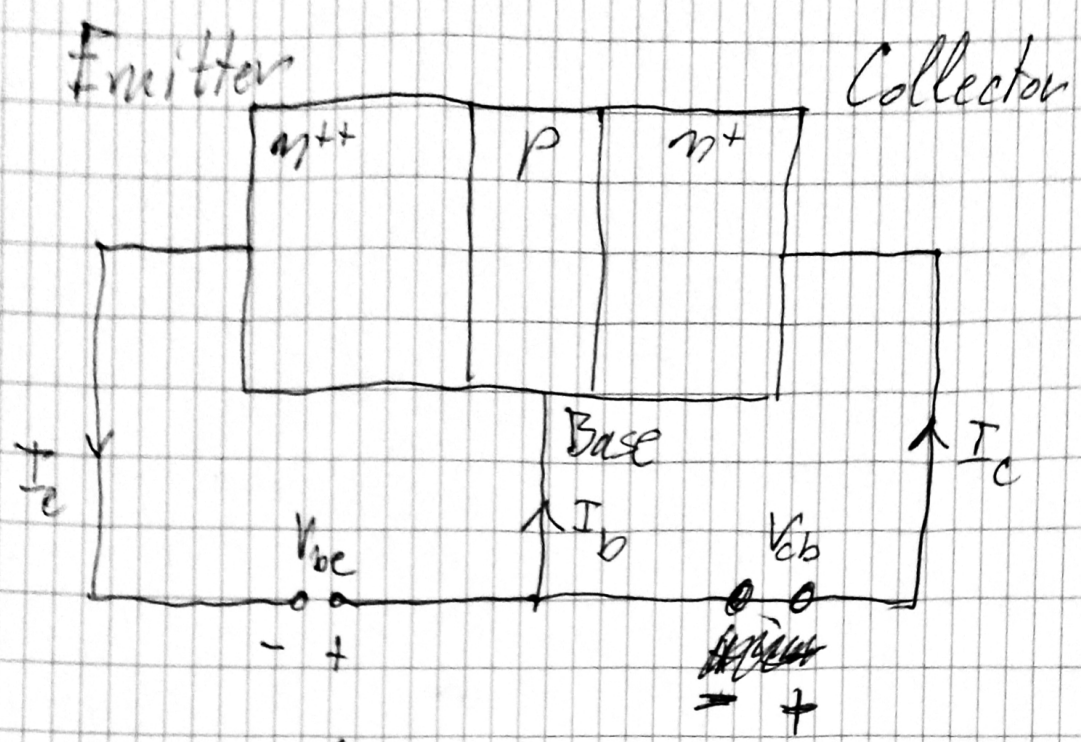
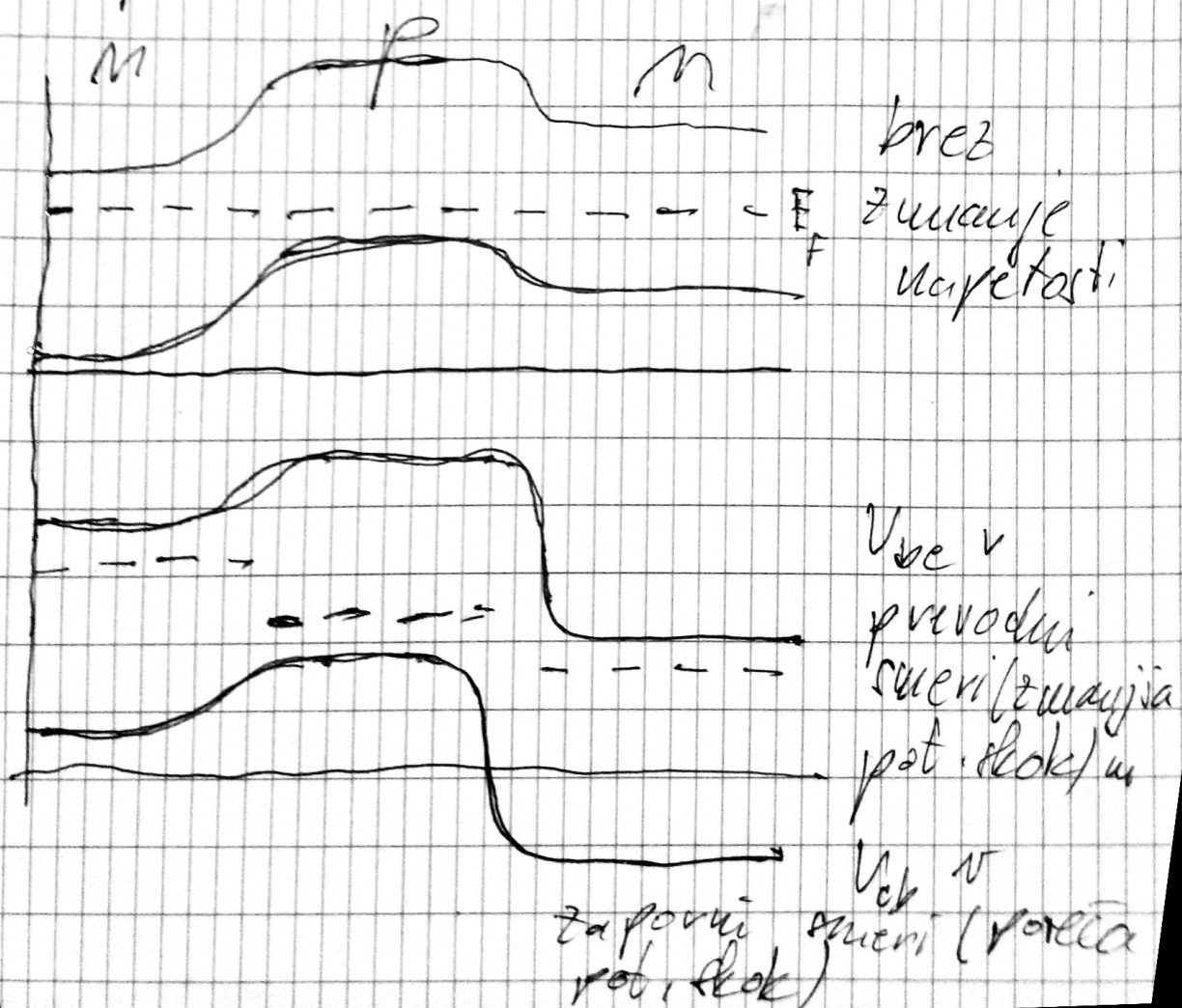


2

Bipolarni tranzistor  
 (BJT = Bipolar Junction Transistor)



n-p-n tranzistor



(b)

$$I_c = \alpha I_e + I_{cb} \approx \alpha I_e$$

$\alpha = 0,95 - 0,98$  majhno ojačanje

$\alpha \approx 0,995$  veliko -"-

$$I_b = I_e - I_c = (1 - \alpha) I_e$$

Stik med E in B v prvotni smeri  $\Rightarrow I_b$  eksp. narasča z  $V_{be}$

$$I_b \approx I_0 e^{V_{be}/kT} \rightarrow$$

$\rightarrow$  znatno višji  $I_e$  in  $I_c$

$$I_e = \frac{I_b}{1 - \alpha}$$

$$I_c = \frac{\alpha}{1 - \alpha} I_b = \frac{\alpha}{1 - \alpha} I_0 e^{V_{be}/kT}$$

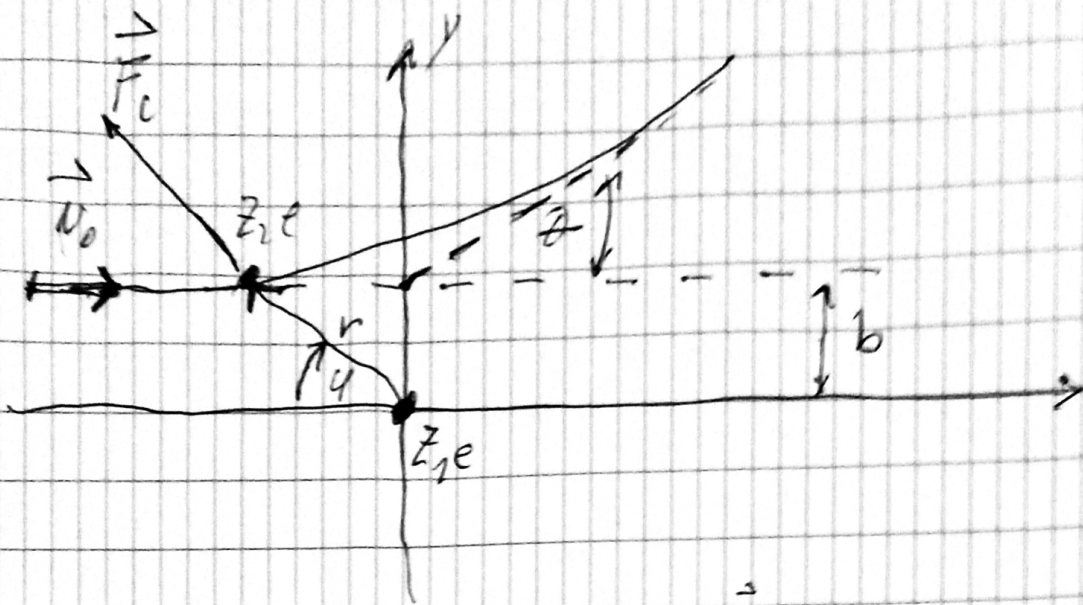
z  $V_{be}$  kvadrirno velat. majhen

$I_b$ , ki pa poveča veliko

večji (50x - 500x)  $I_c$

# Rutherford-ord-ou potkus

(c)



$$F_c = \frac{Z_1 Z_2 e^2}{4\pi\epsilon_0 r^2}$$

$$\frac{d\vec{\Gamma}}{dt} = \vec{M} = \vec{r} \times \vec{F} = \vec{0}$$

$$\vec{\Gamma} = \text{konst.} = \vec{\Gamma}_0$$

$$\vec{\Gamma} = \vec{v} \times \vec{p} = \vec{v} \times m\vec{v}$$

$$x = r \cos \varphi$$

$$y = r \sin \varphi$$

$$\vec{v} = (\dot{x}, \dot{y})$$

$$\Rightarrow \vec{\Gamma} = \dots = m r^2 \dot{\varphi} \vec{e}_z$$

$$\vec{\Gamma}_0 = m v_0 b = m r^2 \dot{\varphi}$$

$$F_{cy} = m \frac{dv_y}{dt} = m \frac{dy}{d\varphi} \dot{\varphi} =$$

$$= \frac{Z_1 Z_2 e^2 \sin \varphi}{4\pi\epsilon_0 r^2}$$

$$4\pi\epsilon_0 r^2$$

$$r^2 = \frac{v_0 b}{\dot{\varphi}}$$

$$\frac{Z_1 Z_2 e^2}{4\pi\epsilon_0} \sin \varphi \frac{\dot{\varphi}}{v_0 b} = m \frac{dv_y}{d\varphi} \dot{\varphi}$$

$$\int_0^{\varphi} dN_y = \frac{z_1 z_2 e^2}{4\pi\epsilon_0 m v_0^2 b} \int_0^{\varphi} \sin\varphi d\varphi$$

$$N_y = \frac{K}{v_0} (1 - \cos\varphi)$$

$$N_y(\varphi = \pi - \theta) = v_0 \sin\theta = \cancel{K(1 - \cos\theta)}$$

$$K(1 + \cos\theta)$$

$$K(1 + \cos\theta) = v_0 \sin\theta$$

$$\frac{K}{v_0} = \frac{z_1 z_2 e^2}{4\pi\epsilon_0 m v_0^2 b} = \frac{\sin\theta}{1 + \cos\theta} = \tan\frac{\theta}{2}$$

$$b = \frac{z_1 z_2 e^2}{4\pi\epsilon_0 m v_0^2} \frac{1}{\tan\frac{\theta}{2}}$$

↓  
vpadni parameter

Če imamo, en sipalni center (en atom Au) se vsi He ioni z vpadnim parameterom med  $b$  in  $b + \Delta b$  sipajo pod kotom  $\theta$  in  $\theta + d\theta$ .

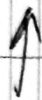
$$db \propto \frac{d\theta}{\tan \frac{\theta}{2}} \frac{1}{\cos^2 \frac{\theta}{2}} = \frac{d\theta}{\sin \frac{\theta}{2}} \quad (e)$$

Če so projektili enakomerno porazdeljeni po površini;

$$dN \propto 2\pi b db \propto \frac{1}{\tan \frac{\theta}{2}} \frac{d\theta}{\sin \frac{\theta}{2}}$$

$\underbrace{\hspace{10em}}_b \quad \underbrace{\hspace{10em}}_{db}$

$$\frac{dN}{d\Omega} \propto \frac{dN}{\sin \theta d\theta} \propto \frac{dN}{2 \sin \frac{\theta}{2} \cos \frac{\theta}{2} d\theta}$$



št. projektilov sipanih v prostoru kot  $d\Omega$  (med  $\theta$  in  $\theta + d\theta$ )

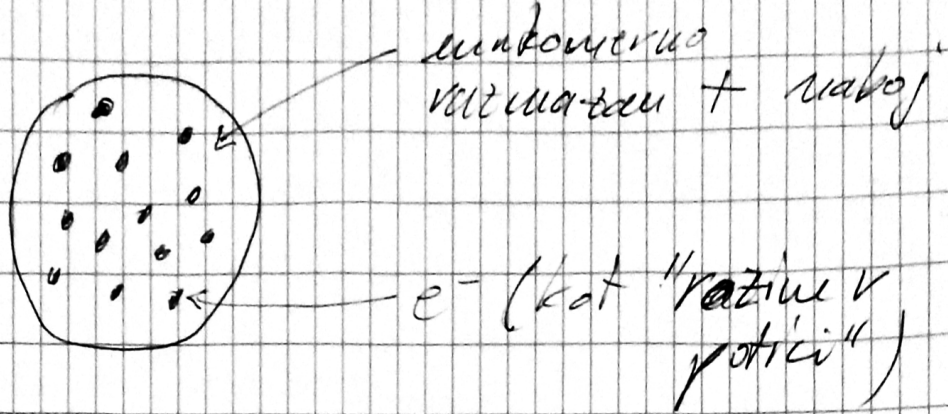
$$\frac{dN}{d\Omega} \propto \frac{\cos \frac{\theta}{2}}{\sin \frac{\theta}{2}} \frac{d\theta}{\sin \frac{\theta}{2}} \frac{1}{\sin \frac{\theta}{2} \cos \frac{\theta}{2}}$$

$\underbrace{\hspace{10em}}_b \quad \underbrace{\hspace{10em}}_{db} \quad \underbrace{\hspace{10em}}_{d\Omega}$

$$\frac{dN}{d\theta} \propto \frac{1}{\sin^2 \frac{\theta}{2}} \quad !!$$

(F)

# Thompson-ov model atoma



Najveća šeta, ki bi jo občutil  
projektiv (če pozabimo  $e^-$ ):

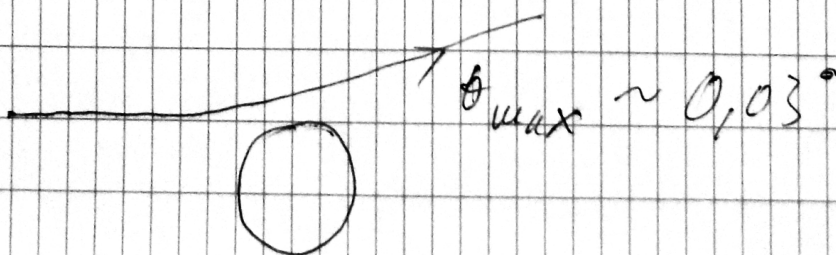
$$F = \frac{Z_1 Z_2 e^2}{4\pi\epsilon_0 R^2} \quad \left. \begin{array}{l} \\ \end{array} \right\} \text{ radij atoma}$$

(pri  $r < R$  bi občutil le naboj  
pri radijalu  $r$ )

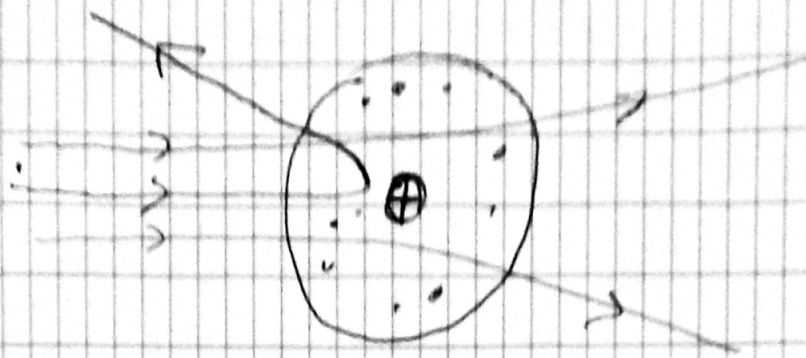
$$\Delta p = F \Delta t \sim \frac{Z_1 Z_2 e^2}{4\pi\epsilon_0 R^2} \frac{2R}{v}$$

$$\theta \sim \frac{\Delta p}{p} \sim \frac{Z_1 Z_2 e^2}{4\pi\epsilon_0 R^2} \frac{2R}{mv} \frac{1}{v} \sim$$

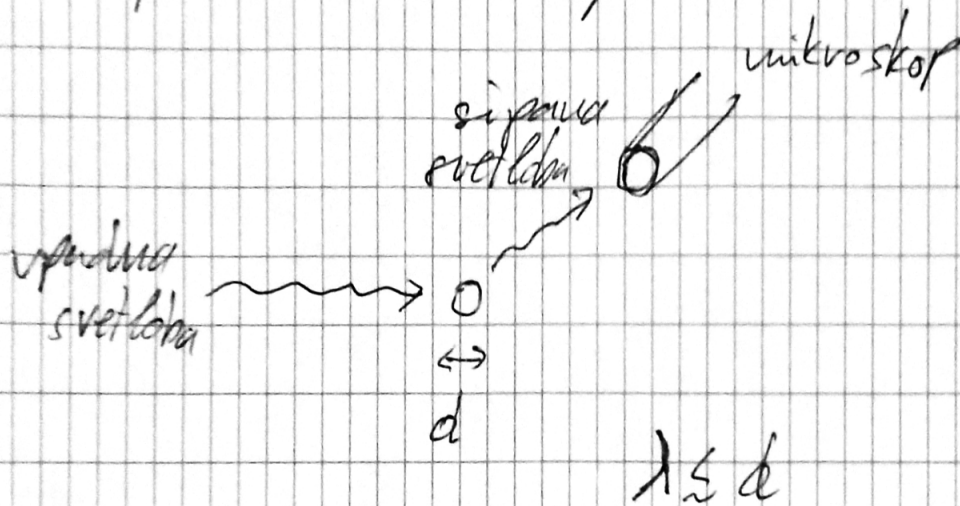
$$\sim 0,03^\circ!$$



# Rutherford-ov model



## Optični mikroskop:



## Valovno-korpuskularni dualizem (-:-)

delec = gib. količina  $p$

$$\lambda_B = \frac{h}{p} = \frac{2\pi h}{p}$$

da "otipljemo" predmete z  $d \sim 10^{-14} \text{ m}$

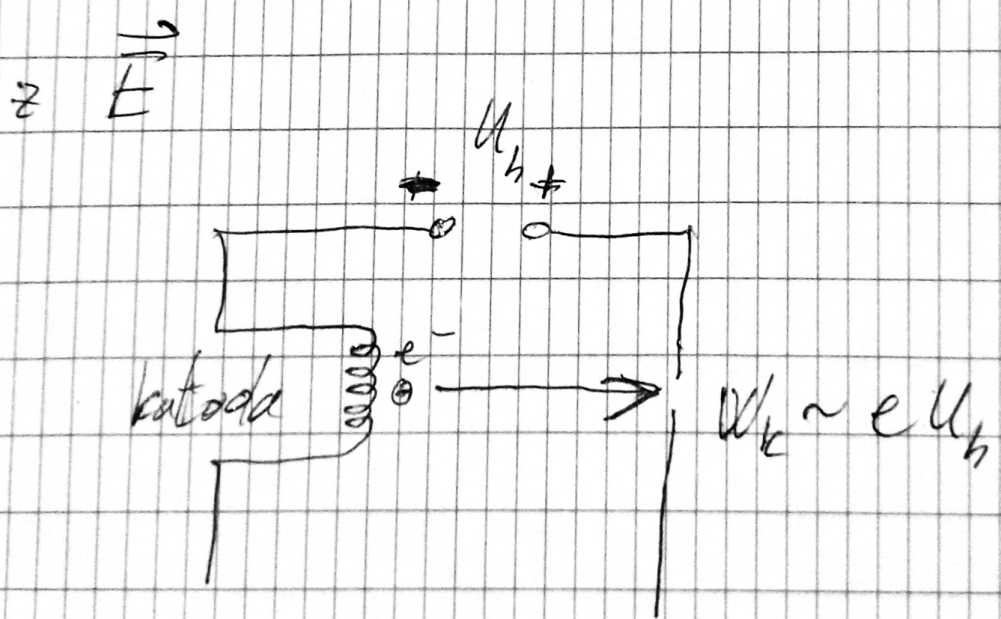
$$\Rightarrow p = \frac{2\pi h}{d} \quad cp \sim \frac{2\pi hc}{d} \sim 120 \text{ MeV}$$

(h)

če uporabimo pospešene  $e^-$   
z 10x višjo energijo \*  $\Rightarrow$   
 $\Rightarrow$  "otipljeno" lahko dnto  $10^{-15}$  m

\*  $E = \sqrt{m^2 c^4 + c^2 p^2} \approx cp$   $e^-$  se sipajo  
(Coulombsko) na  
parazdelitvi nabija v jedru  $\rightarrow$   
 $\rightarrow$  parazdelitev sipanj  $e^-$  med  
informacijo o  $S(r)$

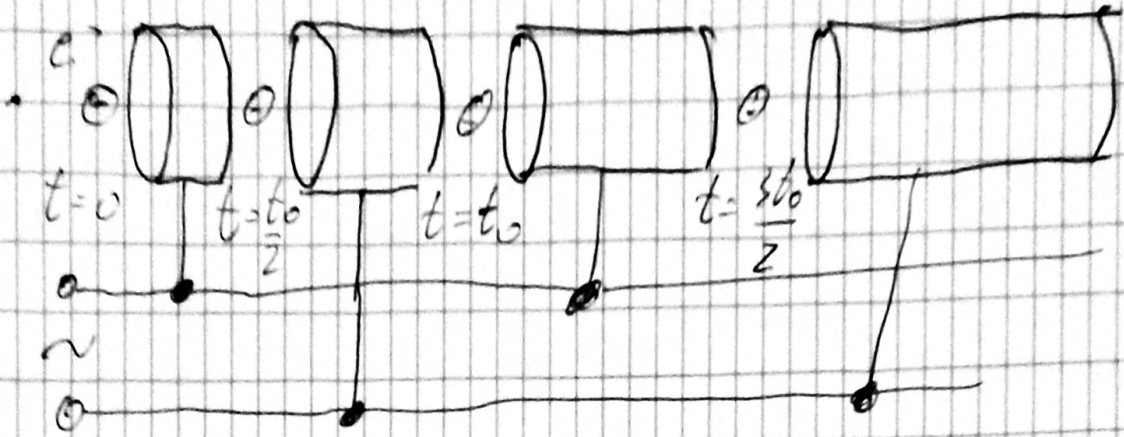
Pospeševanje nabijih delcev



več <sup>ali</sup> stopenj:



(6)



$$U = U_0 \sin(\omega t + \varphi)$$

$$t=0 \quad + \quad - \quad + \quad -$$

$$\frac{t_0}{2} \quad - \quad + \quad - \quad +$$

$$t_0 \quad + \quad - \quad + \quad -$$

$$\text{za } N \ll C \quad d_n = N_n \frac{t_0}{2} = \frac{t_0}{2} \sqrt{\frac{2U_{k,m}}{m}}$$

$$U_{k,m} = e \left[ |U_0 \sin \varphi| + |U_0 \sin(\frac{\omega t_0}{2} + \varphi)| + |U_0 \sin(\omega t_0 + \varphi)| + \dots \right] =$$

$$= e U_0 \sum_{n=0}^N |\sin(\frac{n \omega t_0}{2} + \varphi)| =$$

$$= e U_0 \sum_{n=0}^N \left| \sin n \frac{\omega t_0}{2} \cos \varphi + \cos n \frac{\omega t_0}{2} \sin \varphi \right|$$

$$= e U_0 \sum_{n=0}^N |\sin \alpha y| = e U_0 \frac{(\sin \alpha y)}{|\sin \alpha y|} \quad \textcircled{j}$$

$$l_n \propto \sqrt{n+1}$$